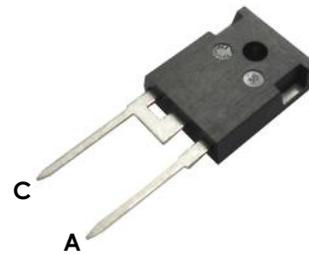


**PRELIMINARY DATASHEET**
**1200V 30A Silicon Carbide Schottky Diode,  
 In TO247 B1 version**
**APPLICATIONS**

- Switch mode power supplies (SMPS)
- Power factor correction (PFC)
- Motor drives
- High speed rectifiers
- Uninterruptible power supplies (UPS)
- Induction heating
- Solar inverter


**FEATURES**

- 175 °C maximum junction temperature
- Extremely fast switching independent with temperature
- Positive temperature coefficient for safe operation and ease of paralleling
- No reverse recovery or forward recovery
- Pb-free finished; **RoHS compliant**


**MAXIMUM RATINGS**

| Parameter   | Symbol         | Value      | Units            |
|---|----------------|------------|------------------|
| Repetitive peak reverse voltage   | $V_{RRM}$      | 1200       | V                |
| DC forward current<br>$T_C = 130\text{ }^\circ\text{C}$<br>$T_C = 25\text{ }^\circ\text{C}$                     | $I_{F(AV)}$    | 30<br>90   | A                |
| Surge non-repetitive forward current, half sine wave<br>$T_C = 25\text{ }^\circ\text{C}$ , $t_p = 8.3\text{ms}$ | $I_{FSM}$      | 142        |                  |
| Operating junction and storage temperature range  | $T_j, T_{stg}$ | -55 to 175 | $^\circ\text{C}$ |

**Thermal Characteristics**

| Parameter                            | Symbol     | Max. Value | Units              |
|--------------------------------------|------------|------------|--------------------|
| <b>Characteristics</b>               |            |            |                    |
| Thermal resistance, junction to case | $R_{thJC}$ | 0.5        | $^\circ\text{C/W}$ |

Electrical Characteristics, at  $T_j = 25^\circ\text{C}$ , unless otherwise specified

| Parameter  | Symbol | Value  |            |            | Unit          |
|--|--------|--------|------------|------------|---------------|
|  |        | Min.   | Typ.       | Max.       |               |
| <b>Static Characteristics</b>  |        |        |            |            |               |
| Reverse leakage current<br>$V_R = 1200\text{V}, T_j = 25^\circ\text{C}$<br>$V_R = 1200\text{V}, T_j = 175^\circ\text{C}$   | $I_R$  | -<br>- | -<br>-     | 500<br>700 | $\mu\text{A}$ |
| Forward voltage drop<br>$I_F = 30\text{A}, T_j = 25^\circ\text{C}$<br>$I_F = 30\text{A}, T_j = 175^\circ\text{C}$  | $V_F$  | -<br>- | 1.7<br>2.8 | 2.0<br>-   | V             |
| <b>Dynamic Characteristics</b>   |        |        |            |            |               |
| Total capacitive charge<br>$V_R = 600\text{V}, I_F = 30\text{A}, T_j = 25^\circ\text{C}, di/dt = 150\text{A}/\mu\text{s}$<br>$V_R = 600\text{V}, I_F = 30\text{A}, T_j = 175^\circ\text{C}, di/dt = 150\text{A}/\mu\text{s}$ | $Q_C$  | -<br>- | 65<br>66   | -<br>-     | nC            |

Figure 1 – Typical Forward voltage drop vs forward current

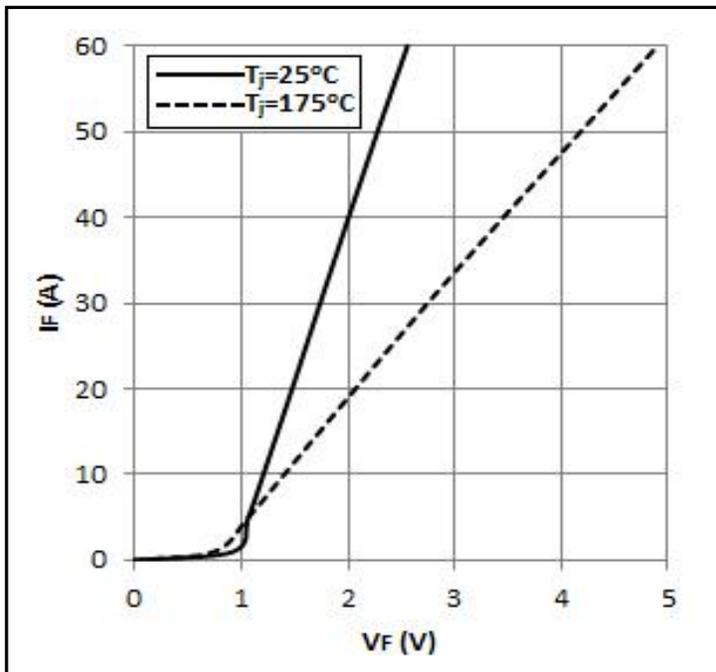
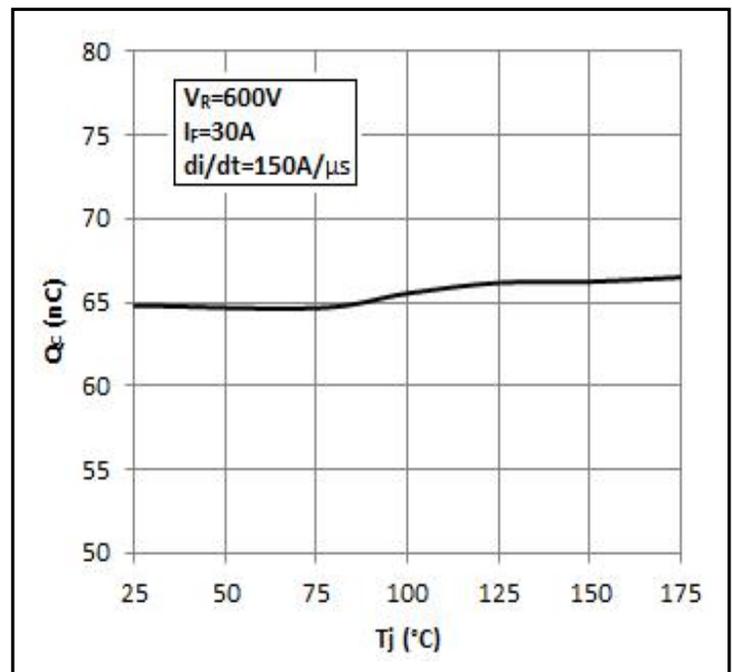
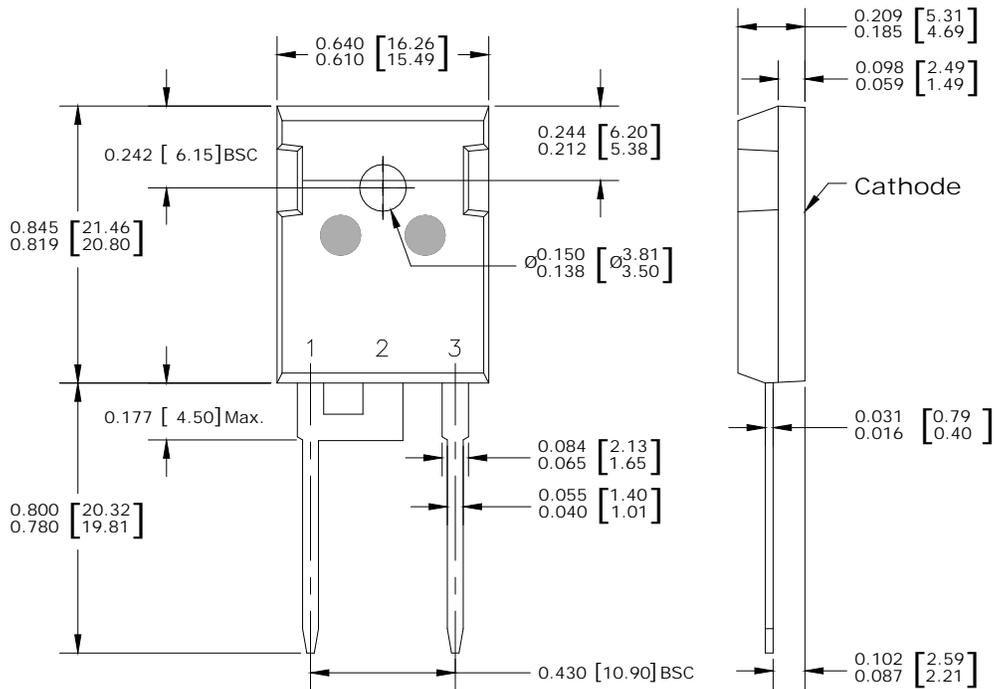


Figure 2 – Capacitive charge vs Junction temperature



**Package Outline Drawing**



**Disclaimer**

These specifications may not be considered as a guarantee of components characteristics. Components have to be tested depending on intended application as adjustments may be necessary. The use of **iQXPRZ Power Inc.** components in life support appliances and systems are subject to written approval of **iQXPRZ Power Inc.**